

# NLV17SZ32

## Single 2-Input OR Gate

The NLV17SZ32 is a single 2-input OR Gate in three tiny footprint packages. The device performs much as LCX multi-gate products in speed and drive. They should be used wherever the need for higher speed and drive are needed.

### Features

- Tiny SOT-353 Package
- 2.4 ns  $T_{PD}$  at 5.0 V (typ)
- Source/Sink 24 mA at 3.0 V
- Over-Voltage Tolerant Inputs
- Pin For Pin with NC7SZ32P5X, TC7SZ32FU
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V  $V_{CC}$  Operation
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free, Beryllium Free and are RoHS Compliant

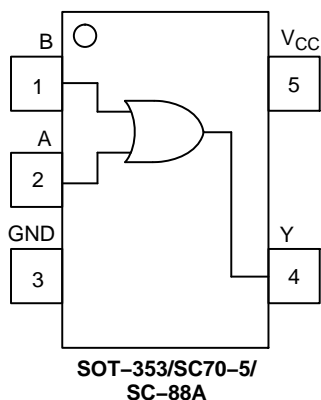


Figure 1. Pinouts (Top View)

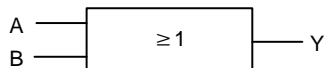


Figure 2. Logic Symbol

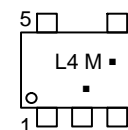


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1  
SC-88A  
(SC-70-5/SOT-353)  
DF SUFFIX  
CASE 419A

### MARKING DIAGRAMS



L4 = Specific Device Marking

M = Date Code\*

■ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

# NLV17SZ32

## PIN ASSIGNMENT (SOT-353/SC70-5/SC-88A)

Pin	Function
1	B
2	A
3	GND
4	Y
5	V <sub>CC</sub>

## FUNCTION TABLE

Input		Output Y = A + B
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

## MAXIMUM RATINGS

Symbol	Parameter	Value	Units
V <sub>CC</sub>	DC Supply Voltage	−0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage	−0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage	−0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	DC Input Diode Current	−50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>OUT</sub> < GND, V <sub>OUT</sub> > V <sub>CC</sub>	±50	mA
I <sub>OUT</sub>	DC Output Sink Current	±50	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	−65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T <sub>J</sub>	Junction Temperature Under Bias	+150	°C
θ <sub>JA</sub>	Thermal Resistance (Note 1)	350	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	186	mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification Human Body Model (Note 2) Machine Model (Note 3)	4000 400	V
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below GND at 125°C (Note 4)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
4. Tested to EIA/JESD78.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Units
$V_{CC}$	DC Supply Voltage	1.65	5.5	V
$V_{IN}$	DC Input Voltage	0	5.5	V
$V_{OUT}$	DC Output Voltage	0	5.5	V
$T_A$	Operating Temperature Range	-55	+125	°C
$t_r, t_f$	Input Rise and Fall Time $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	$V_{CC}$ (V)	$T_A = 25^\circ\text{C}$			$-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		Units
				Min	Typ	Max	Min	Max	
$V_{IH}$	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	$0.75 V_{CC}$ $0.7 V_{CC}$			$0.75 V_{CC}$ $0.7 V_{CC}$		V
$V_{IL}$	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			$0.25 V_{CC}$ $0.3 V_{CC}$		$0.25 V_{CC}$ $0.3 V_{CC}$	V
$V_{OH}$	High-Level Output Voltage $V_{IN} = V_{IL} \text{ or } V_{IH}$	$I_{OH} = -100 \mu\text{A}$ $I_{OH} = -3 \text{ mA}$ $I_{OH} = -8 \text{ mA}$ $I_{OH} = -12 \text{ mA}$ $I_{OH} = -16 \text{ mA}$ $I_{OH} = -24 \text{ mA}$ $I_{OH} = -32 \text{ mA}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	$V_{CC} - 0.1$ 1.29 1.9 2.2 2.4 2.3 3.8	$V_{CC}$ 1.52 2.1 2.4 2.7 2.5 4.0		$V_{CC} - 0.1$ 1.29 1.9 2.2 2.4 2.3 3.8		V
$V_{OL}$	Low-Level Output Voltage $V_{IN} = V_{IH} \text{ or } V_{OH}$	$I_{OL} = 100 \mu\text{A}$ $I_{OL} = 3 \text{ mA}$ $I_{OL} = 8 \text{ mA}$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 16 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 32 \text{ mA}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5		 0.08 0.20 0.22 0.28 0.38 0.42	 0.1 0.24 0.3 0.4 0.4 0.55 0.55		 0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
$I_{IN}$	Input Leakage Current	$V_{IN} = 5.5 \text{ V or GND}$	0 to 5.5			$\pm 0.1$		$\pm 1.0$	$\mu\text{A}$
$I_{OFF}$	Power Off Leakage Current	$V_{IN} = 5.5 \text{ V or } V_{OUT} = 5.5 \text{ V}$	0			1		10	$\mu\text{A}$
$I_{CC}$	Quiescent Supply Current	$V_{IN} = 5.5 \text{ V or GND}$	5.5			1		10	$\mu\text{A}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

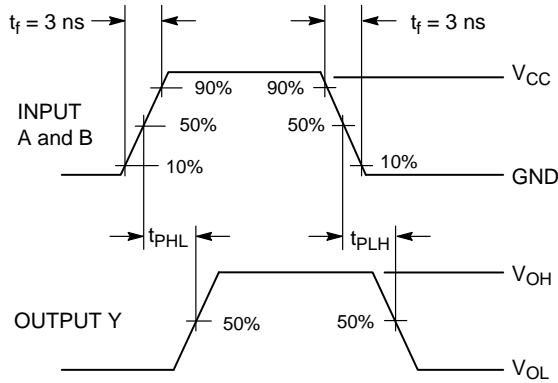
**AC ELECTRICAL CHARACTERISTICS**  $t_R = t_F = 3.0 \text{ ns}$

Symbol	Parameter	Condition	$V_{CC}$ (V)	$T_A = 25^\circ\text{C}$			$-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		Units
				Min	Typ	Max	Min	Max	
$t_{PLH}$ $t_{PHL}$	Propagation Delay (Figure 3 and 4)	$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	1.65	2.0	5.5	12.0	2.0	12.7	ns
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	1.8	2.0	4.6	10	2.0	10.5	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	$2.5 \pm 0.2$	0.8	3.0	7	0.8	7.5	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	$3.3 \pm 0.3$	0.5	2.6	4.7	0.5	5.0	
		$R_L = 500 \text{ }\Omega, C_L = 50 \text{ pF}$	1.5	3.0	5.2	1.5	5.5		
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	$5.0 \pm 0.5$	0.5	2.2	4.1	0.5	4.4	
		$R_L = 500 \text{ }\Omega, C_L = 50 \text{ pF}$		0.8	2.4	4.5	0.8	4.8	

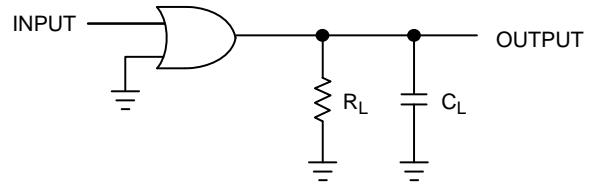
**CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
$C_{IN}$	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	>4	pF
$C_{PD}$	Power Dissipation Capacitance (Note 5)	10 MHz, $V_{CC} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	25	pF
		10 MHz, $V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	30	

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPER)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption;  $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$ .



**Figure 3. Switching Waveform**



A 1 MHz square input wave is recommended for propagation delay tests.

**Figure 4. Test Circuit**

**ORDERING INFORMATION**

Device Order Number	Package Type	Tape and Reel Size†
NLV17SZ32DFT2G*	SC-88A/SC-70-5/SOT-353 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

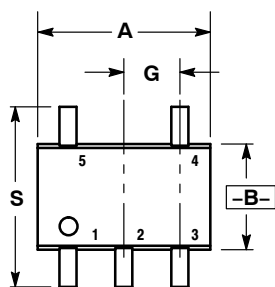
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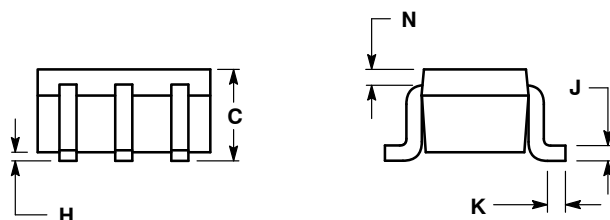
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SC-88A (SC-70-5/SOT-353)  
CASE 419A-02  
ISSUE L

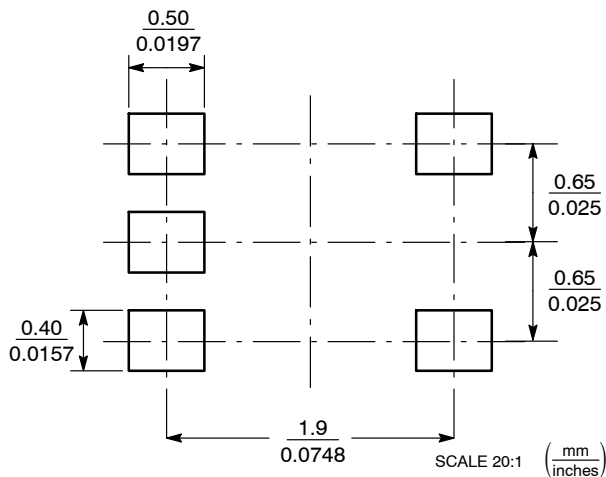
DATE 17 JAN 2013



D 5 PL  $\oplus$  0.2 (0.008) (M) B (M)



## SOLDER FOOTPRINT



STYLE 1:  
PIN 1. BASE  
2. EMITTER  
3. BASE  
4. COLLECTOR  
5. COLLECTOR

STYLE 2:  
PIN 1. ANODE  
2. EMITTER  
3. BASE  
4. COLLECTOR  
5. CATHODE

STYLE 3:  
PIN 1. ANODE 1  
2. N/C  
3. ANODE 2  
4. CATHODE 2  
5. CATHODE 1

STYLE 4:  
PIN 1. SOURCE 1  
2. DRAIN 1/2  
3. SOURCE 1  
4. GATE 1  
5. GATE 2

STYLE 5:  
PIN 1. CATHODE  
2. COMMON ANODE  
3. CATHODE 2  
4. CATHODE 3  
5. CATHODE 4

STYLE 6:  
PIN 1. EMITTER 2  
2. BASE 2  
3. EMITTER 1  
4. COLLECTOR  
5. COLLECTOR 2/BASE 1

STYLE 7:  
PIN 1. BASE  
2. EMITTER  
3. BASE  
4. COLLECTOR  
5. COLLECTOR

STYLE 8:  
PIN 1. CATHODE  
2. COLLECTOR  
3. N/C  
4. BASE  
5. EMITTER

STYLE 9:  
PIN 1. ANODE  
2. CATHODE  
3. ANODE  
4. ANODE  
5. ANODE

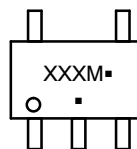
Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

## NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- 419A-01 OBSOLETE. NEW STANDARD 419A-02.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

## GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION: SC-88A (SC-70-5/SOT-353)

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